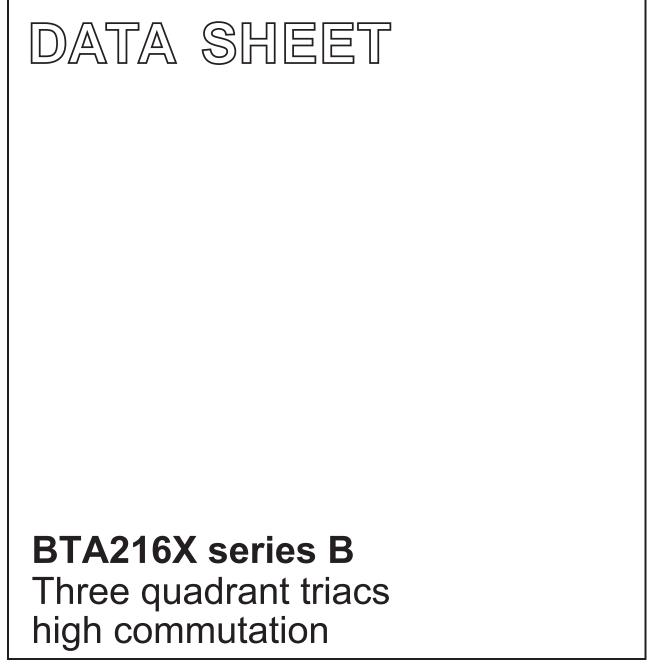
DISCRETE SEMICONDUCTORS



Product specification

October 1997



## **BTA216X series B**

### **GENERAL DESCRIPTION**

Glass passivated high commutation triacs in a full pack, plastic envelope intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

### **PINNING - SOT186A**

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
case	isolated

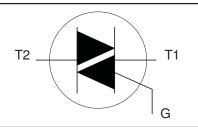
### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V <sub>DRM</sub> I <sub>T(RMS)</sub> I <sub>TSM</sub>	BTA216X- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	<b>500B</b> 500 16 140	<b>600B</b> 600 16 140	<b>800B</b> 800 16 140	V A A

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**PIN CONFIGURATION** 

### SYMBOL



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	v
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave;	-		16		A
I <sub>TSM</sub>	Non-repetitive peak on-state current	$T_{hs} \le 38 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge t = 20 ms	-		140		А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 16.7 ms t = 10 ms	-		150 98		A A <sup>2</sup> s
dl <sub>⊤</sub> /dt	Repetitive rate of rise of on-state current after triggering	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-		100		Α/μs
$\begin{matrix} I_{GM} \\ V_{GM} \\ P_{GM} \\ P_{G(AV)} \end{matrix}$	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period	- - -		2 5 5 0.5		A V W W
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature	penou	-40 -		150 125		Ĵ Ĵ

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

### BTA216X series B

**ISOLATION LIMITING VALUE & CHARACTERISTIC** 

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. $\leq 65\%$ ; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air	- -	- - 55	4.0 5.5 -	K/W K/W K/W

### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$				
GI		T2+G+	2	18	50	mA
		T2+ G-	222	21	50	mA
		T2- G-	2	34	50	mA
l,	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$				
-		T2+G+	-	31	60	mA
		T2+ G-	-	34	90	mA
		T2- G-	-	30	60	mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	31	60	mA
V <sub>⊤</sub>	On-state voltage	$I_{T} = 20 \text{ A}$	-	1.2	1.5	V
V <sub>GT</sub>	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.7	1.5	V
		$V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{L} = 125 \text{ °C}$	0.25	0.4	-	V
I <sub>D</sub>	Off-state leakage current	$V_{D} = V_{DRM(max)}; T_{j} = 125 °C$	-	0.1	0.5	mA

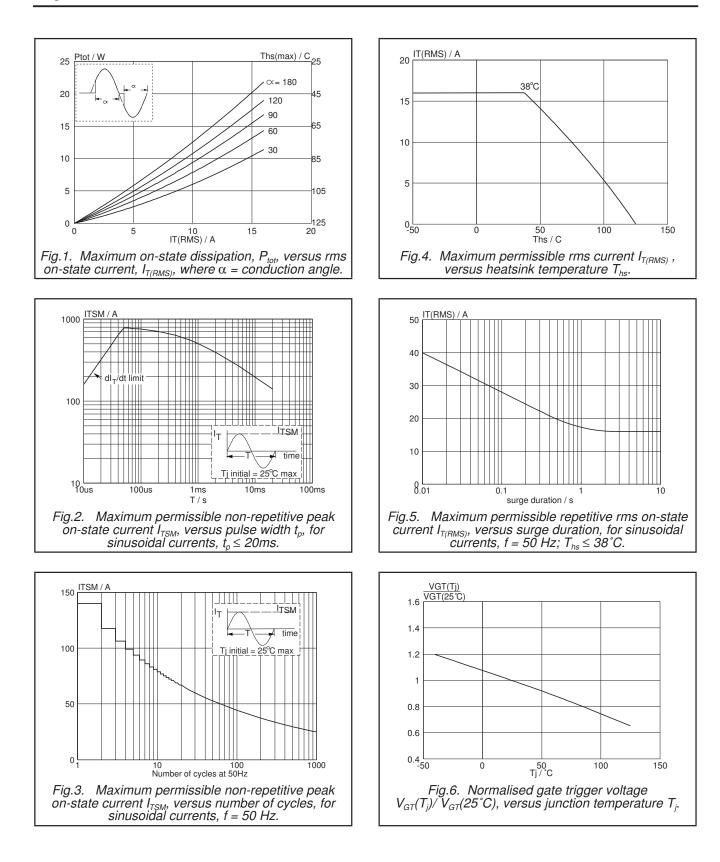
### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

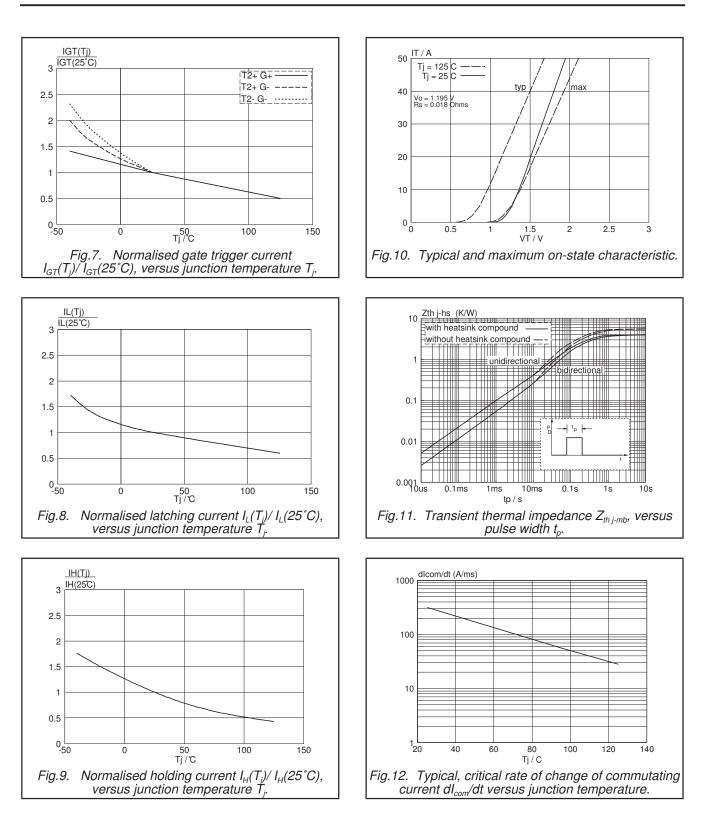
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	1000	4000	-	V/µs
dl <sub>com</sub> /dt	off-state voltage Critical rate of change of commutating current	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C}; I_{T(RMS)} = 16 \text{ A};$ without snubber; gate open circuit	-	28	-	A/ms
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs

**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

### BTA216X series B



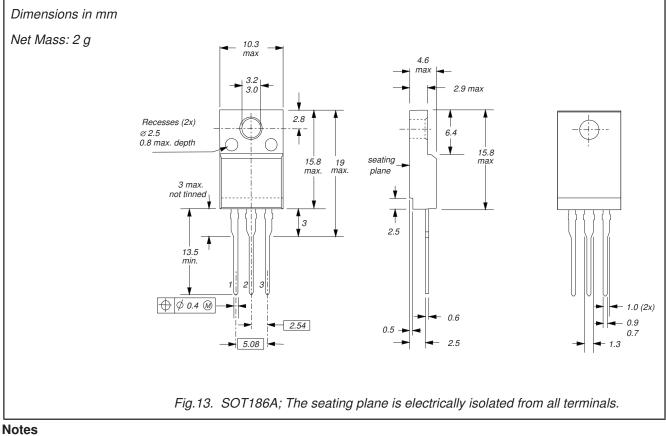
### BTA216X series B



BTA216X series B

# Three quadrant triacs high commutation

### **MECHANICAL DATA**



Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

## Legal information

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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